iM7133

N-Channel Enhancement Mode MOSFET

Datasheet

1. Product Information

1.1 Features

- Advanced Trench Cell Design
- RoHS Compliant and Halogen Free
- Moisture Sensitivity Level MSL1



1.2 Package Type

TOLLB-8L

1.3 Quick Reference

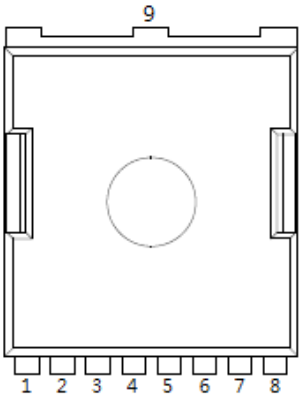
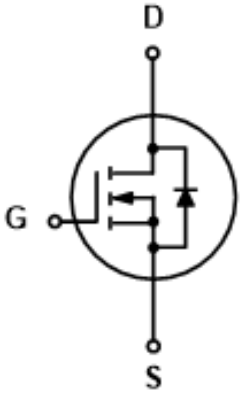
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Limiting Values						
P_{tot}	Total Power Dissipation	T_C = 25 ℃	-	-	300	W
I_{DS}	Drain-Source Current	T_C = 25 ℃, V_{GS} = 10 V	-	-	170	A
		T_C = 100 ℃, V_{GS} = 10 V	-	-	120	
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS} = 0 V, I_{DS} = 250 μA	150	-	-	V
$V_{GS(th)}$	Gate-Source Threshold Voltage	V_{DS} = V_{GS}, I_{DS} = 250 μA	3	-	5	
$R_{DS(ON)}$	Drain-Source On-State Resistance	V_{GS} = 10 V, I_{DS} = 50 A	-	3.4	4.3	mΩ
		V_{GS} = 8 V, I_{DS} = 30 A		3.7	5.0	

2. Ordering Code & Marking Information

Ordering Code	Marking Information
iM7133	iM7133 XXXXX X: Date Code

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3. Pin Description

Pin	Description	Simplified Outline	Symbol
1	Gate(G)		
2~8	Source(S)		
9	Drain(D)		

4. Limiting Values

Symbol	Parameter		Rating	Unit
V_{DS}	Drain-Source Voltage		150	V
V_{GS}	Gate-Source Voltage		± 20	
I_{DS}	Drain-Source Current	T_C = 25 ℃, V_{GS} = 10 V	170	A
		T_C = 100 ℃, V_{GS} = 10 V	120	
I_{DM}[Note1]	Pulsed Drain-Source Current	T_C = 25 ℃, V_{GS} = 10 V	460	A
I_S	Diode Forward Current	T_C = 25 ℃, V_{GS} = 0 V	170	
E_{AS}	Single Pulsed Avalanche Energy	L = 1.0 mH, V_{DD} = 50 V	1624	mJ
P_{tot}	Total Power Dissipation	T_C = 25 ℃	300	W
$R_{\theta JA}$[Note2]	Thermal Resistance- Junction to Ambient		44	℃ / W
$R_{\theta JC}$	Thermal Resistance- Junction to Case		0.5	
T_{stg}	Storage Temperature		- 55 ~ 175	℃
T_J	Junction Temperature		175	

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5. Electrical Characteristics (T_A = 25 °C Unless Otherwise Noted)

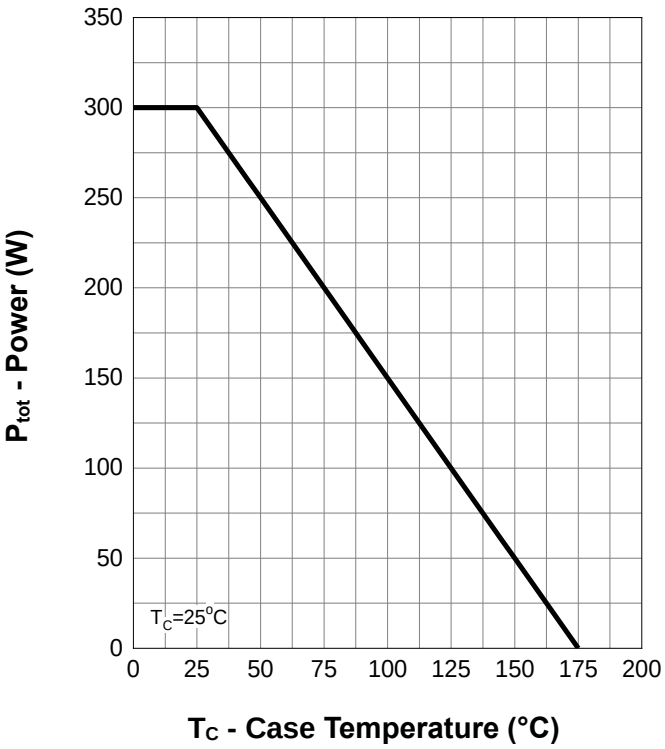
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS} = 0 V, I_{DS} = 250 μA	150	-	-	V
$V_{GS(th)}$	Gate-Source Threshold Voltage	V_{DS} = V_{GS}, I_{DS} = 250 μA	3	-	5	
I_{DSS}	Drain-Source Leakage Current	V_{DS} = 120 V, V_{GS} = 0 V	-	-	1	μA
I_{GSS}	Gate-Source Leakage Current	V_{DS} = 0 V, V_{GS} = ± 20 V	-	-	±100	nA
$R_{DS(ON)}$	Drain-Source On-State Resistance	V_{GS} = 10 V, I_{DS} = 50 A	-	3.4	4.3	mΩ
		V_{GS} = 8 V, I_{DS} = 30 A	-	3.7	5.0	
Diode Characteristics						
V_{SD}	Diode Forward Voltage	I_{SD} = 50 A, V_{GS} = 0 V	-	-	1.3	V
t_{rr}[Note3]	Reverse Recovery Time	I_{DS} = 50 A, V_{GS} = 0 V, dI_{SD}/dt = 100 A/μs	-	113	-	nS
Q_{rr}[Note3]	Reverse Recovery Charge		-	522	-	nC
Dynamic Characteristics[Note3]						
C_{iss}	Input Capacitance	V_{GS} = 0 V, V_{DS} = 75 V, Frequency = 1 MHz	-	9534	-	pF
C_{oss}	Output Capacitance		-	764	-	
C_{rss}	Reverse Transfer Capacitance		-	49	-	
t_d(on)	Turn-on Delay Time	V_{DS} = 75 V, V_{GEN} = 10 V, R_G = 3.9 Ω, R_L = 1.5 Ω, I_{DS} = 50 A	-	33	-	nS
t_r	Turn-on Rise Time		-	111	-	
t_d(off)	Turn-off Delay Time		-	69	-	
t_f	Turn-off Fall Time		-	58	-	
Gate Charge Characteristics[Note3]						
Q_g	Total Gate Charge	V_{DS} = 75 V, V_{GS} = 10 V, I_{DS} = 50 A	-	140	-	nC
Q_{gs}	Gate-Source Charge		-	63	-	
Q_{gd}	Gate-Drain Charge		-	33	-	

Note 1：Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.
Note 2：Surface Mounted on 1 in^2 pad area, t ≤ 10 sec.
Note 3：Guaranteed by design, not subject to production testing.

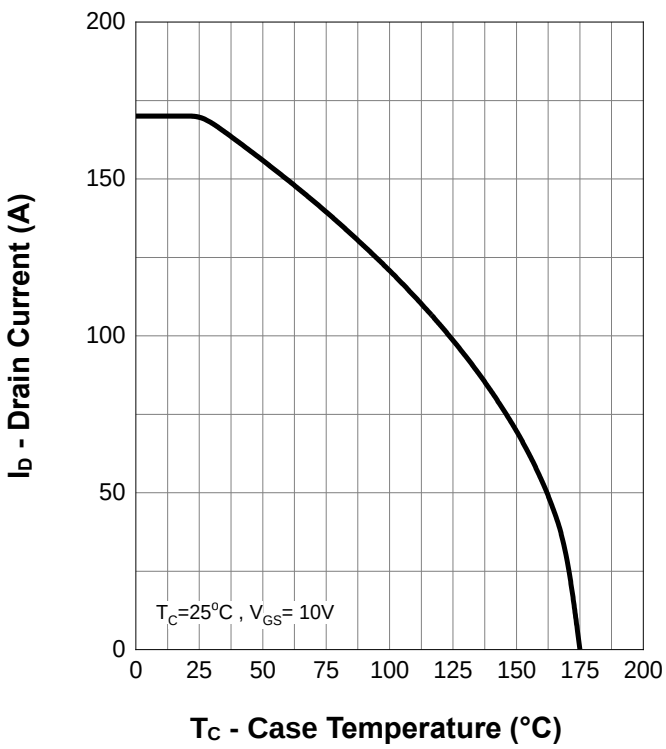
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6. Typical Characteristics

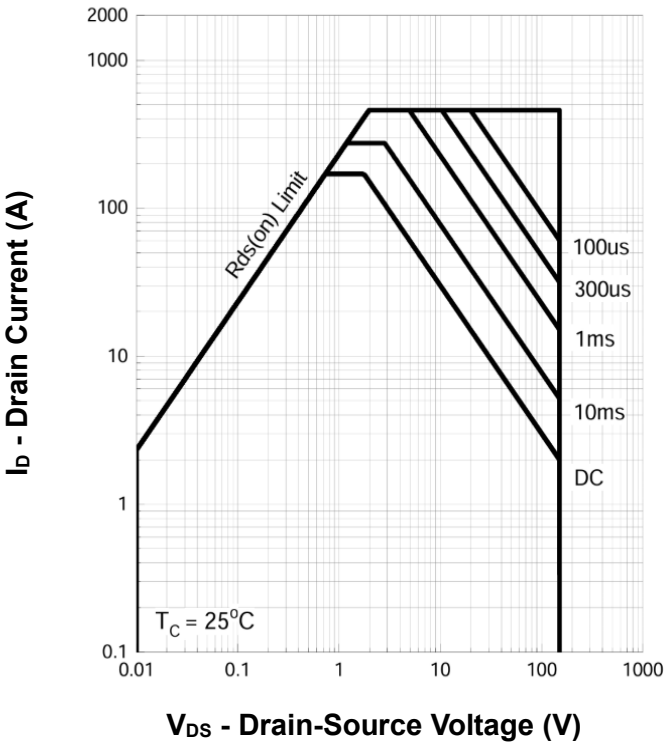
Power Capability



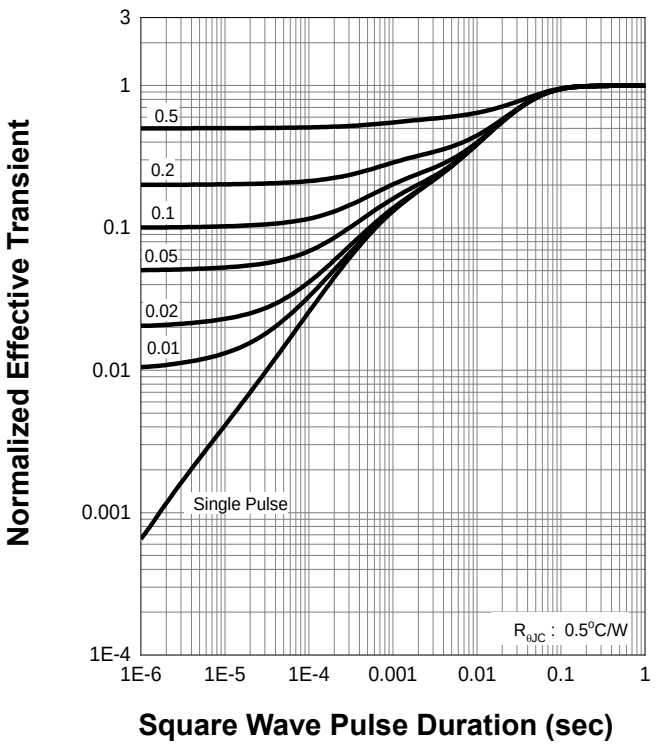
Current Capability



Safe Operating Area



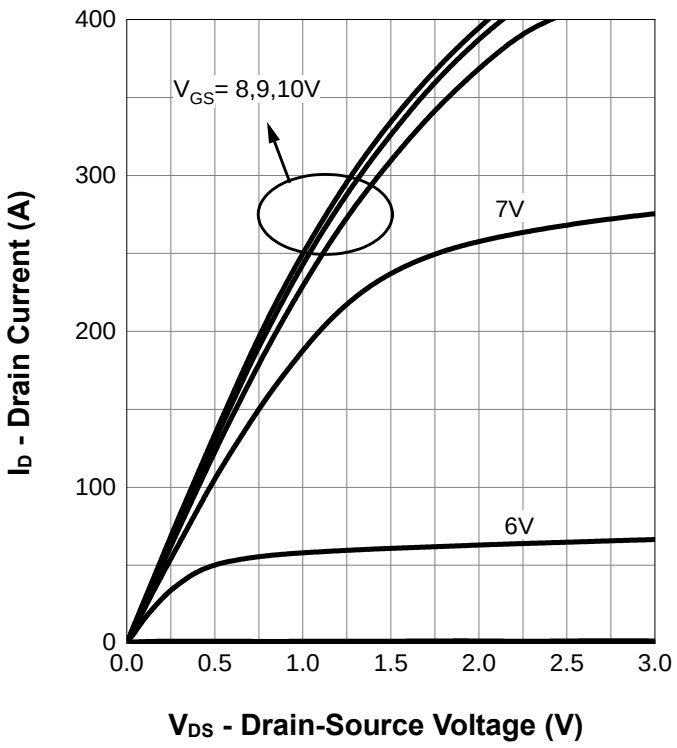
Transient Thermal Impedance



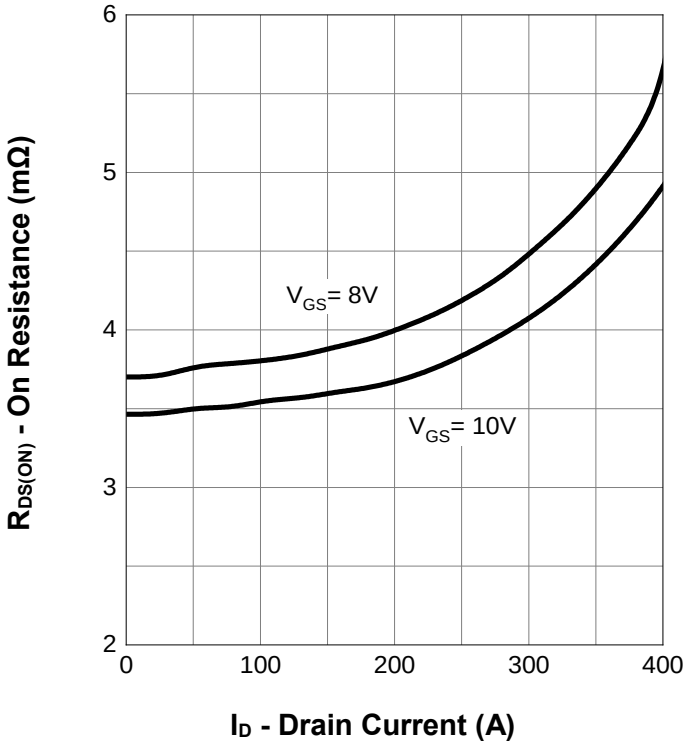
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6. Typical Characteristics (cont.)

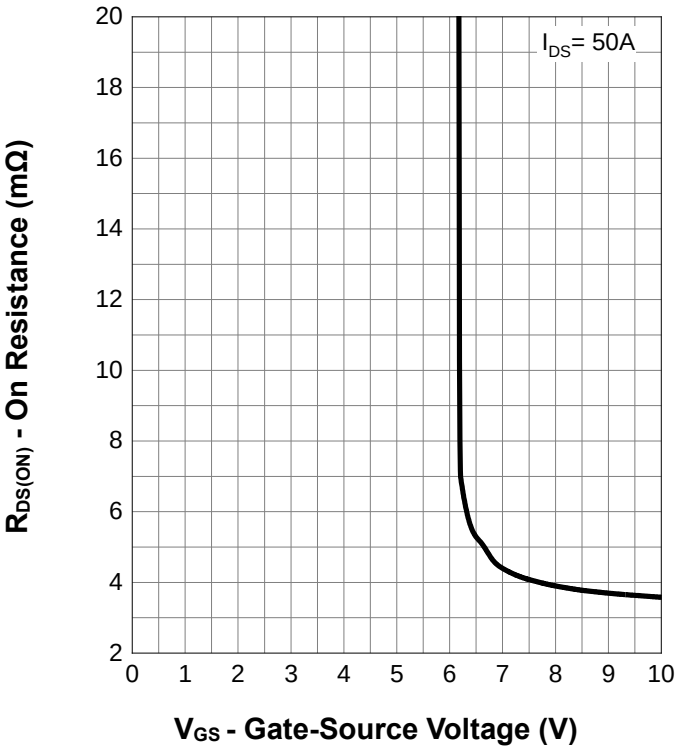
Output Characteristics



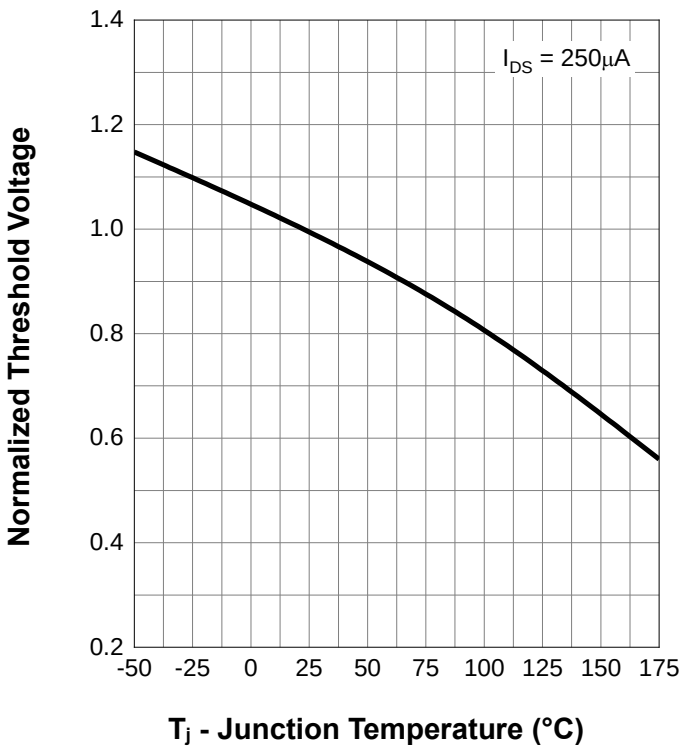
On Resistance



Transfer Characteristics

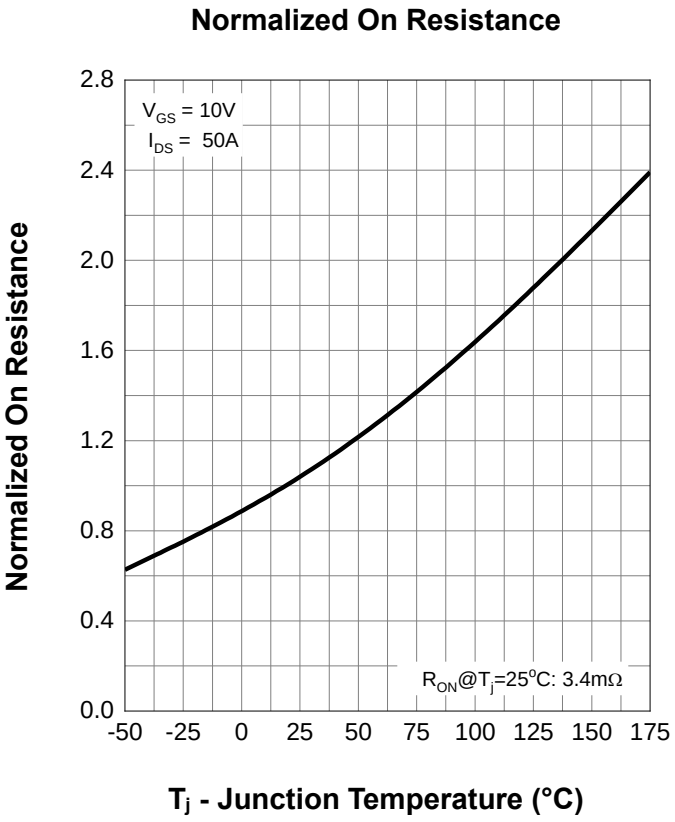


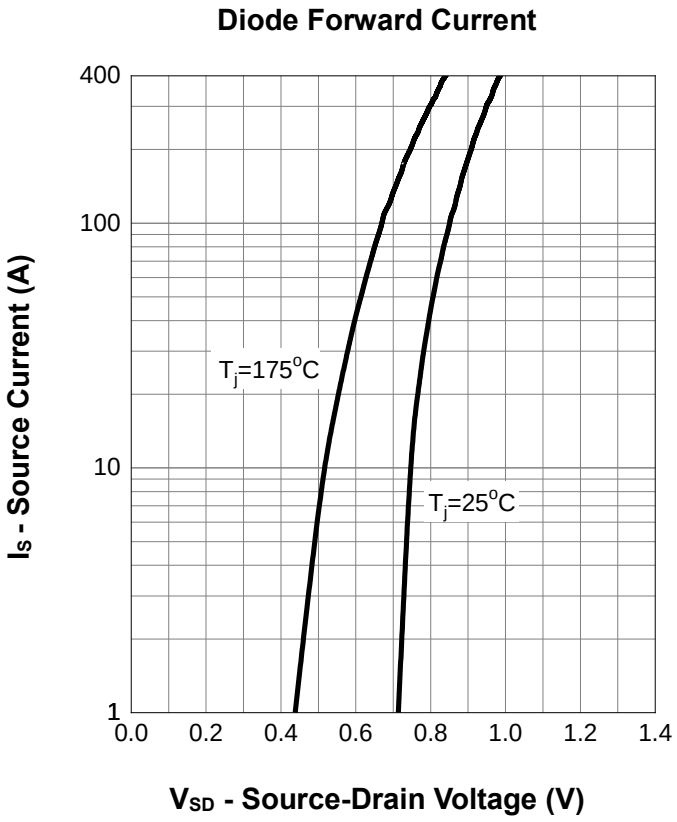
Normalized Threshold Voltage

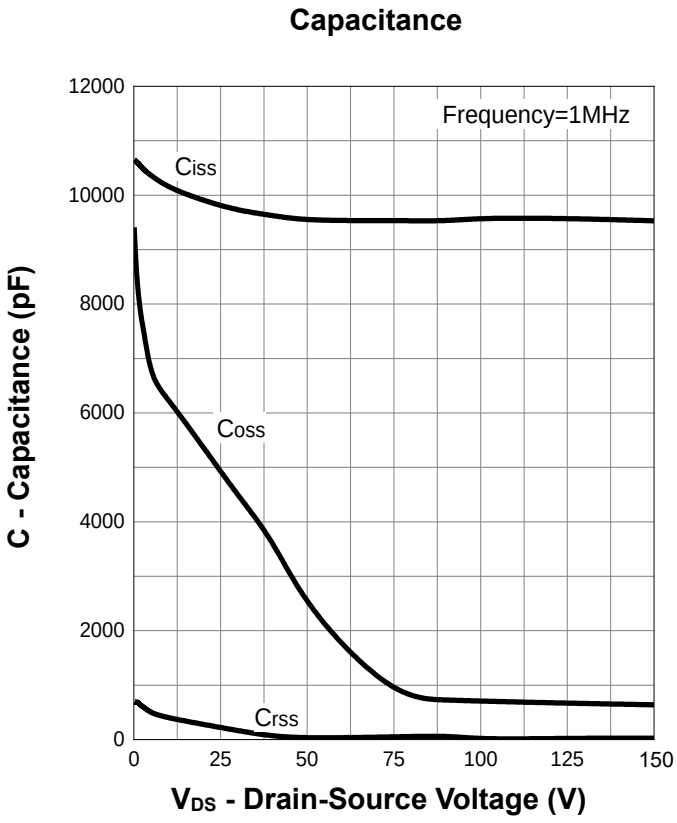


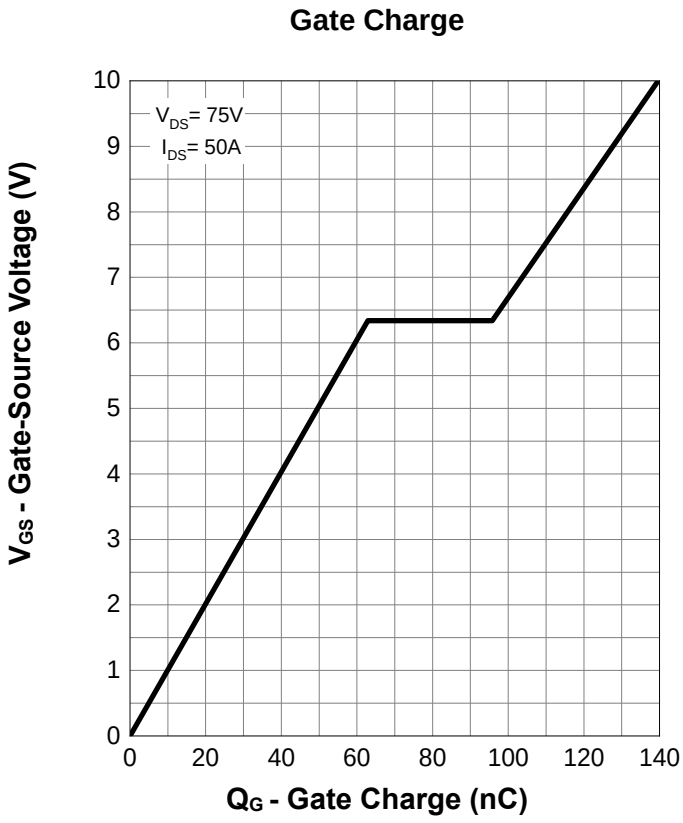
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6. Typical Characteristics (cont.)









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